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Declarations under Rule 4.17:

- as to applicant's entitlement to apply for and be granted a patent (Rule 4.17(ii))

[Continued on next page]

(54) **Title:** APPARATUS AND METHOD FOR TEMPERATURE CONTROL OF A SEMICONDUCTOR SUBSTRATE SUPPORT

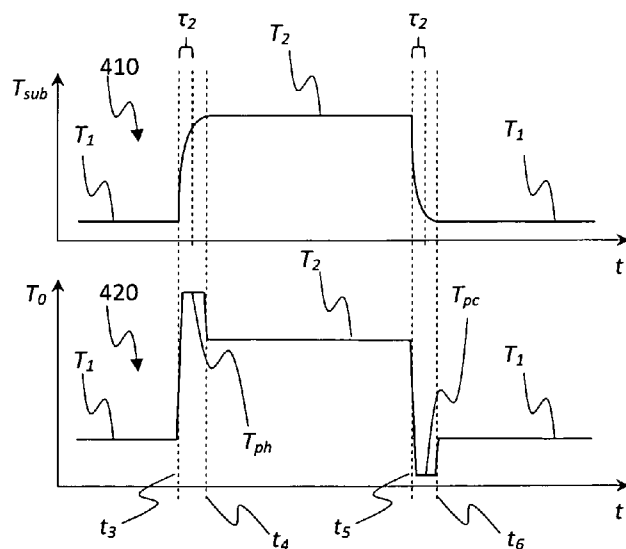


Fig. 4

(57) **Abstract:** A recirculation system of a substrate support on which a semiconductor substrate is subjected to a multistep process in a vacuum chamber, the system comprising a substrate support having at least one liquid flow passage in a base plate thereof, an inlet and an outlet in fluid communication with the flow passage, a supply line in fluid communication with the inlet, and a return line in fluid communication with the outlet; a first recirculator providing liquid at temperature T_1 in fluid communication with the supply line and the return line; a second recirculator providing liquid at temperature T_2 in fluid communication with the supply line and the return line, temperature T_2 being at least 10°C above temperature T_1 ; a pre-cooling unit providing liquid at temperature T_{pc} connected to the inlet and the outlet, temperature T_{pc} being at least 10°C below T_1 ; a pre-heating unit providing liquid at temperature T_{ph} connected to the inlet and the outlet, temperature T_{ph} being at least 10°C above T_2 ; a controller operable to selectively operate valves of the recirculation system to recirculate liquid between the flow passage and the first recirculator, the second recirculator, the pre-cooling unit or the pre-heating unit.



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- *as to the applicant's entitlement to claim the priority of the earlier application (Rule 4.17(iii))*
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